

University of Groningen

Incommensurate structures and physical properties of antimony, bismuth and lanthanum misfit layer compounds.

Ren, Y; Haas, C

IMPORTANT NOTE: You are advised to consult the publisher's version (publisher's PDF) if you wish to cite from it. Please check the document version below.

Document Version

Publisher's PDF, also known as Version of record

Publication date:

1996

[Link to publication in University of Groningen/UMCG research database](#)

Citation for published version (APA):

Ren, Y., & Haas, C. (1996). *Incommensurate structures and physical properties of antimony, bismuth and lanthanum misfit layer compounds*. s.n.

Copyright

Other than for strictly personal use, it is not permitted to download or to forward/distribute the text or part of it without the consent of the author(s) and/or copyright holder(s), unless the work is under an open content license (like Creative Commons).

The publication may also be distributed here under the terms of Article 25fa of the Dutch Copyright Act, indicated by the "Taverne" license. More information can be found on the University of Groningen website: <https://www.rug.nl/library/open-access/self-archiving-pure/taverne-amendment>.

Take-down policy

If you believe that this document breaches copyright please contact us providing details, and we will remove access to the work immediately and investigate your claim.

Downloaded from the University of Groningen/UMCG research database (Pure): <http://www.rug.nl/research/portal>. For technical reasons the number of authors shown on this cover page is limited to 10 maximum.

$\text{TiS}_2)_n$ ($n=1,2$)

they found a
 $1/\tau(T) \propto T^{1.5}$
obtained by fit-
[125]. A linear
some high T_c

Summary

age-1 and stage-
measurements.
which are mu-
s an ordering of
contacts which
efficient measure-
the TiS_2 sand-
dependence of tem-
clearly indicates
em. The varia-
y the expression
a. Furthermore,
nds show a qua-
evidence for the
with the misfit
a frequency in-
hibit non-linear
 S_2 , investigated
ical field paral-
ndicular to the

Already before the discovery that crystals diffract X-rays, the morphology of crystals was explained with the three-dimensional (3D) repetition of a smallest unit. After this discovery (1912) the diffraction pattern could be explained with 3D periodicity and crystal structures were determined on basis of a unit cell and a space group. However, it was also known that the morphology of some crystals did not obey the laws for 3D periodicity. An example is AuTe_2 for which it was known already in 1902 that some of the crystal planes could not be indexed with the three integer Miller indices appropriate for most of the planes. This led to the discovery of incommensurately modulated crystals. They show a diffraction pattern that consists of the main reflections of a 3D periodic lattice and in addition weak extra reflections, satellites. The complete set of reflections can be indexed with three integer indices for the 3D lattice and an extra index for a modulation wave vector. Because a 3D periodic repetition is absent and there is yet a sharp diffraction pattern, the crystals are called quasi-periodic.

A second group of quasi-periodic crystals are the composite or intergrowth compounds. In contrast to the incommensurately modulated crystals the diffraction pattern consists of main reflections of two (or more) 3D patterns, and in addition satellites. One finds composite structures for inorganic as well as organic compounds. Subject of this thesis are the so-called misfit layer compounds which are built of a stacking of sandwiches with composition \mathcal{TX}_2 and double layers with composition \mathcal{MX} ; the formula giving the composition of the composite crystal is $(\mathcal{MX})_{1+\delta}(\mathcal{TX}_2)_n$. \mathcal{M} can be one of the elements Sn, Pb, Sb, Bi and the rare earth metals; \mathcal{T} the transition elements Ti, V, Cr, Nb, Ta; \mathcal{X} is S or Se. The index δ depends on the constituents \mathcal{MX} and \mathcal{TX}_2 in the compounds. The two types of building units, each with a unit cell and space group, are called the subsystems. The three-layer thick \mathcal{TX}_2 sandwiches are similar to those in the pure dichalcogenides \mathcal{TX}_2 . The \mathcal{MX} subsystem consists of a double layer with a structure resembling a two-atom thick slab in NaCl type MX; some pure compounds \mathcal{MX} are also known, most of them have the NaCl-type structure. Besides compounds with a stacking of one \mathcal{TX}_2 sandwich followed by one \mathcal{MX} layer, there are also compounds with a stacking of two or even

three \mathcal{TX}_2 sandwiches followed by one \mathcal{MX} double layer, etc. Such staged structures are also found for intercalation compounds of the transition metal dichalcogenides; they have foreign atoms or molecules in the gap (van de Waals gap) between the \mathcal{TX}_2 sandwiches. When all gaps are filled one has stage-1 compounds; if the gaps are alternately filled and empty, a stage-2 compound. The misfit layer compounds can be considered to be a special kind of intercalation compounds of the transition metal dichalcogenides \mathcal{TX}_2 . The \mathcal{MX} lattice is pseudo-tetragonal, the \mathcal{TX}_2 lattice pseudo-hexagonal. For that reason the two types of layers do not fit. There in one direction (\vec{a} axis) along which the atoms of the two subsystems run parallel, however, with a different periodicity (the misfit). The relation between the unit cell vectors of the two subsystems can most simply be expressed in reciprocal space, viz., there is a common reciprocal plane, which is the (\vec{b}^*, \vec{c}^*) plane. The common \vec{c}^* is due to space filling (layers which are stacked along the c axes cannot intersect); the common \vec{b}^* by the interaction between the sublattices along the parallel \vec{a} axes. Both lattices modulate each other incommensurately; it means that the atoms are somewhat displaced from their positions in the 3D unit cell. This modulation gives rise to satellites in the diffraction pattern. For the composite crystals a new crystallography was developed by Janner and Janssen as an extension of the theory for incommensurately modulated crystals developed by de Wolff, Janner and Janssen. The theory makes use of higher dimensional (super) space. The theory was extended by van Smaalen, Kato and Yamamoto. A program (JANA) for the structure determination of composite crystals from X-ray data was developed by Petricek.

The first compound of the class of misfit layer compounds is $(\text{LaS})_{1.20}\text{CrS}_2$ discovered by Kato *et al.* (1977). Investigations starting at about 1988 showed that there is large number of misfit layer compounds. Compounds with NbX_2 or TaX_2 sandwiches are orthorhombic or monoclinic; the Nb (Ta) atom is in approximately trigonal-prismatic coordination by chalcogen. These compounds show metallic type electrical conduction. Compounds with TiX_2 , VX_2 or CrX_2 sandwiches have the transition metal in approximately octahedral coordination by chalcogen. They have monoclinic or triclinic subsystems. Compounds with a CrX_2 subsystem only occur with Bi or a rare earth metal; they were found to be semiconductors.

The chemical bonding has been elucidated in particular by photoelectron spectroscopy and recently by band structure calculations. For compounds with Sn, Pb, Bi there is a slight electron donation from the \mathcal{MX} to the \mathcal{TX}_2 layers and the weak bonding between the layers is mainly covalent. A large electron donation from the \mathcal{MX} to the \mathcal{TX}_2 sandwiches and strong interlayer interaction is found if \mathcal{M} is a rare earth metal.

This thesis describes the syntheses, structure determinations in superspace symmetry and physical properties of a number of new misfit layer compounds. The first examples of compounds with SbS double layers and TiS_2 sandwiches were prepared, viz.,

$(\text{SbS})_{1.15}(\text{TiS}_2)_2$, v
The SbS layers ha
the Bi compounds
modulated due to
lar to the diagonal
the incommensura
superspace group i
showed that there
and zig-zag chains
Waals interaction.
types of Sb atoms,
those in the zig-zag
terminations using
and UPS showed a
in the TiS_2 conduct
(resistivity, Hall eff
4 – 350 K. Both co
donation of electron
and ~ 0.3 e/Ti for
dependence given b
of a two-dimensional
cal reflectivity show
compared to the Dr

The compound $(\text{BiS})_{1.11}(\text{VSe})_2$ sandwiched layer and a VS_2 sandwiched layer were found in BiX compounds. The structure could not be elucidated.

Vanadium compounds with VS_2 sandwiches a transition metal sandwiched layer structure was found for $(\text{BiS})_{1.11}(\text{VSe})_2$.

An accurate structure determination of $(\text{LaSe})_{1.11}(\text{TiS}_2)_2$ double layer sandwiched structure was found. The structure is modulated from the LaSe to the TiS_2 layers. The LaSe double layer contains vacancies in the Se^{2-} sites. The largest modulation is in the TiS_2 layers. The two subsystems are incommensurate since in all other c

aged structures
 chalcogenides;
) between the
 ds; if the gaps
 yer compounds
 the transition
 he \mathcal{TX}_2 lattice
 . There in one
 rallel, however,
 t cell vectors of
 , viz., there is a
 is due to space
 e common \vec{b}^* by
 n lattices modu-
 ewhat displaced
 satellites in the
 was developed
 arately modula-
 y makes use of
 Smaalen, Kato
 n of composite

CrS₂ discovered
 d that there is
 \mathcal{MX}_2 sandwiches
 ately trigonal-
 type electrical
 the transition
 ave monoclinic
 ar with Bi or a

n spectroscopy
 , Pb, Bi there
 weak bonding
 he \mathcal{MX} to the
 e earth metal.

ace symmetry
 e first exam-
 prepared, viz.,

(SbS)_{1.15}(TiS₂)₂, with $n = 1$ and 2 (stage-1 and stage-2 compounds, respectively). The SbS layers have much more complicated structure than the \mathcal{MX} layers found in the Bi compounds (Bi \mathcal{X})_{1+ δ} \mathcal{TX}_2 with $\mathcal{T} = \text{Nb}$ or Ta . The SbS layers are interface modulated due to antiphase boundaries. These antiphase boundaries are perpendicular to the diagonal in the (\vec{a}, \vec{b}) plane; for the Bi compounds they are perpendicular to the incommensurate \vec{a} axis. As a consequence of this modulation a (3+2)D triclinic superspace group is needed to describe the structure. The refinement of the structure showed that there are zig-zag chains of mainly Sb atoms with distances as in Sb metal and zig-zag chains of mainly sulfur atoms with distances corresponding to van der Waals interaction. A photoelectron spectroscopy study showed that there are two types of Sb atoms, those in a coordination by sulfur as for a normal SbS layer and those in the zig-zag chains; the ratio 22 : 78 is as was found from the structure determinations using X-ray diffraction. The valence band spectrum studied with XPS and UPS showed a peak just below the Fermi level corresponding some Ti 3d electrons in the TiS₂ conduction band. The electrical transport properties of both compounds (resistivity, Hall effect and thermopower) were measured in the temperature range 4 – 350 K. Both compounds showed metallic behavior. The Hall effect showed a donation of electrons from the SbS to the TiS₂ layers (~ 0.6 electron/Ti for $n = 1$ and ~ 0.3 e/Ti for $n = 2$). The resistivity in the (ab) plane shows a temperature dependence given by $\rho = \rho_0 + A_{ee}(T/T_F)^2 \ln(T_F/T)$ for electron-electron scattering of a two-dimensional Fermi-liquid system. From the fit T_F is obtained. The optical reflectivity showed that a much better fit is obtained for a Fermi liquid behavior compared to the Drude model for which the scattering rate is frequency independent.

The compound (BiS)_{1.11}VS₂, the first example of a compound with a Bi \mathcal{X} double layer and a VS₂ sandwich, shows an interface modulated BiS lattice, similar to that found in Bi \mathcal{X} compounds with Nb \mathcal{X}_2 or Ta \mathcal{X}_2 sandwiches. The complete structure could not be elucidated due to disorder in the BiS structure.

Vanadium compounds are interesting because in the series of compounds with \mathcal{TX}_2 sandwiches a transition occurs from metallic behavior for $\mathcal{T} = \text{Ti}$ to semiconducting behavior for $\mathcal{T} = \text{Cr}$. Vanadium compounds are intermediate, metallic behavior was found for (BiS)_{1.11}VS₂.

An accurate structure determination in (3+1)D superspace of a compound with an LaSe double layers and VSe₂ sandwiches showed that there is a large charge transfer from the LaSe to the VSe₂ layers, as also found in other misfit layer compounds with a Ln \mathcal{X} double layer ($Ln = \text{rare earth}$). The structure determination showed that there are vacancies in the La lattice such that charge balance exists between La³⁺, V³⁺, and Se²⁻. The largest displacements of the atoms due to the mutual modulation of the two subsystems are remarkably found at the vanadium atoms, which is quite unusual since in all other cases the largest displacements are found for the atoms close to the

